

SAMTM Data Sheet SAM-1064-20-30ps-x, λ = 1064 nm

Laser wavelength $\lambda = 1064 \text{ nm}$

High reflection band $\lambda = 1020 ... 1100 \text{ nm}$

Absorbance $A_0 = 20 \%$ Modulation depth $\Delta R = 15 \%$ Non-saturable loss $A_{ns} = 5 \%$

Saturation fluence $\Phi_{\text{sat}} = 18 \, \mu\text{J/cm}^2$

Relaxation time constant $\tau \sim 30 \text{ ps}$

Damage threshold $\Phi = 2 \text{ mJ/cm}^2$

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

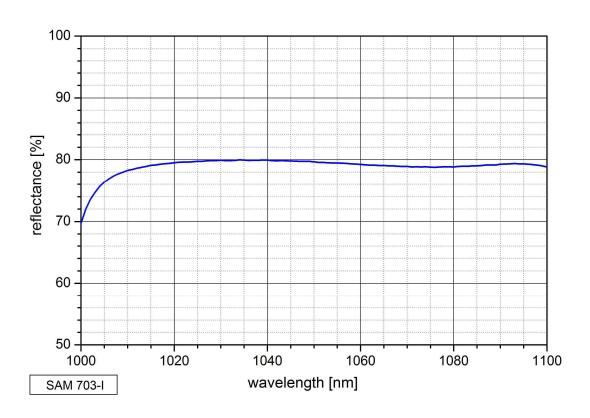
Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0unmountedx = 12.7 gglued on a gold plated Cu-cylinder with 12.7 mm \varnothing x = 25.4 gglued on a gold plated Cu-cylinder with 25.4 mm \varnothing x = 12.7 ssoldered on a gold plated Cu-cylinder with 12.7 mm \varnothing x = 25.4 ssoldered on a gold plated Cu-cylinder with 25.4 mm \varnothing

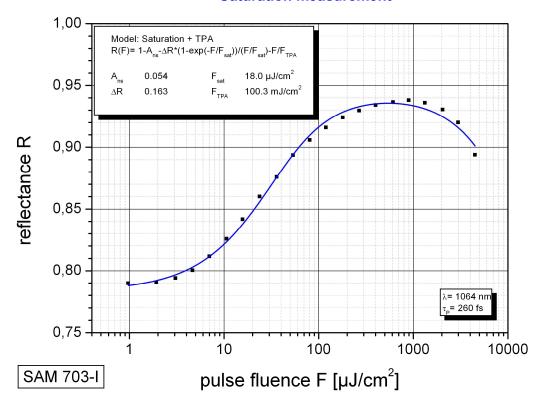
x = FC mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance





Saturation measurement



Pump-probe measurement

